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of 1

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

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Application Number	Ukhiw 509898			
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First Named Inventor	Hiroto OHTAKE			
Art Unit	Unknown 2818			
Examiner Name	Unknown HOANG-QUAN HO			
Attorney Docket Number	Q83944			

U.S. PATENT DOCUMENTS					
Examiner Cite No. 1		Document Number		Publication Date MM-DD-YYYY	
	Number	Kind Code ² (if known)	Name of Patentee or Applicant of Cited Document		
HOIA		US 6,114,250	Α	09-05-2000	Ellingboe et al.
	•	US			
		US			
	-	US		i	·
		US		· -	
		US			·

FOREIGN PATENT DOCUMENTS							
Examiner Cite Initials* No.1	Foreign Patent Document			Publication Date	Name of Patentee or		
	Country Code ³	Number ⁴	Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation ⁶	
HOH		JР	2000-36484	Α	02-02-2000		No
		JР	2001-35832	Α	02-09-2001	·	No
		JР	2000-269185	Α	09-29-2000		No
		JР	2001-351976	Α	12-21-2001		No
		JР	H07-193049	Α .	07-28-1995		No
		JР	2001-351897	Α	12-21-2001		No
		JР	2000-114367	Α	04-21-2000		No
		JP	H10-125783	Α	05-15-1998		No
		JР	H11-297829	Α	10-29-1999		No
1		JР	2003-92287	Α	03-28-2003		No
ACIA		JР	2002-110788	Α	04-12-2002		No
					-		1

NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁶	
HOH		H. Hanahata et al., "Dependency of Basic Properties of Porous Silica ILD Thin Films in the k Range 1.6-2.7 on CMP Compatibility", Conference Proceedings ULSI XVI, 2001, Materials Research Society, page 629.		

Examiner Signature	14-0114	Date Considered	4/3/2006
	7/0		

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